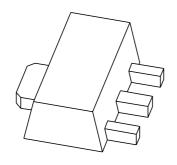
# **DISCRETE SEMICONDUCTORS**

# DATA SHEET



# BCV29; BCV49 NPN Darlington transistors

Product data sheet Supersedes data of 1999 Apr 08

2004 Dec 06



# **NPN Darlington transistors**

**BCV29**; **BCV49** 

### **FEATURES**

- High current (max. 500 mA)
- Low voltage (max. 60 V)
- High DC current gain (min. 20000).

### **APPLICATIONS**

• Preamplifier input applications.

### **DESCRIPTION**

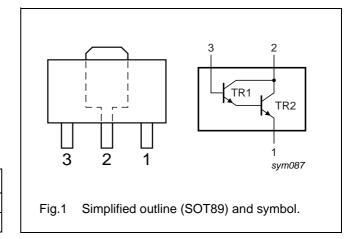
NPN small-signal Darlington transistor in a surface mount SOT89 plastic package. PNP complements: BCV28 and BCV48.

### **MARKING**

TYPE NUMBER	MARKING CODE
BCV29	EF
BCV49	EG

### **PINNING**

PIN	DESCRIPTION
1	emitter
2	collector
3	base



### **ORDERING INFORMATION**

TYPE NUMBER	PACKAGE				
TIPE NOWIBER	NAME	ME DESCRIPTION VERS			
BCV29	SC-62	C-62 plastic surface mounted package; collector pad for good heat			
BCV49		transfer; 3 leads			

# NPN Darlington transistors

BCV29; BCV49

#### LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V <sub>CBO</sub>	collector-base voltage	open emitter			
	BCV29		_	40	V
	BCV49		_	80	V
V <sub>CES</sub>	collector-emitter voltage	$V_{BE} = 0 V$			
	BCV29		_	30	V
	BCV49		_	60	V
V <sub>EBO</sub>	emitter-base voltage	open collector	_	10	V
I <sub>C</sub>	collector current (DC)		_	500	mA
I <sub>CM</sub>	peak collector current		_	1	Α
I <sub>BM</sub>	peak base current		_	200	mA
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C; note 1	_	1.3	W
T <sub>stg</sub>	storage temperature		-65	+150	°C
Tj	junction temperature		_	150	°C
T <sub>amb</sub>	ambient temperature		-65	+150	°C

### Note

### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient	note 1	96	K/W
R <sub>th(j-s)</sub>	thermal resistance from junction to soldering point		16	K/W

### Note

Device mounted on a printed-circuit board, single-sided copper, tin-plated, mounting pad for collector 1 cm<sup>2</sup>.
 For other mounting conditions, see "Thermal considerations for SOT89 in the General Part of associated Handbook".

<sup>1.</sup> Device mounted on a printed-circuit board, single-sided copper, tin-plated, mounting pad for collector 1 cm<sup>2</sup>. For other mounting conditions, see "Thermal considerations for SOT89 in the General Part of associated Handbook".

# NPN Darlington transistors

BCV29; BCV49

### **CHARACTERISTICS**

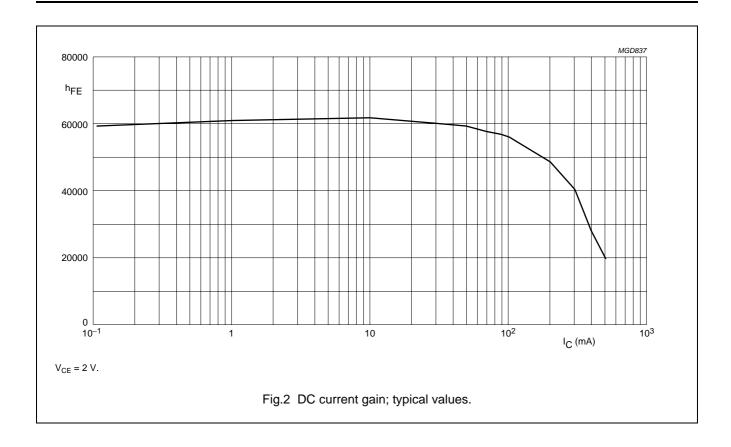
 $T_{amb}$  = 25 °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I <sub>CBO</sub>	collector-base cut-off current					
	BCV29	$I_E = 0 \text{ A}; V_{CB} = 30 \text{ V}$	_	_	100	nA
	BCV49	$I_E = 0 \text{ A}; V_{CB} = 60 \text{ V}$	_	_	100	nA
I <sub>EBO</sub>	emitter-base cut-off current	I <sub>C</sub> = 0 A; V <sub>EB</sub> = 10 V	_	-	100	nA
h <sub>FE</sub>	DC current gain	V <sub>CE</sub> = 5 V; see Fig.2				
	BCV29	I <sub>C</sub> = 1 mA	4000	-	_	
		I <sub>C</sub> = 10 mA	10000	-	_	
		I <sub>C</sub> = 100 mA	20000	-	_	
		I <sub>C</sub> = 500 mA	4000	-	_	
	DC current gain	V <sub>CE</sub> = 5 V; see Fig.2				
	BCV49	I <sub>C</sub> = 1 mA	2000	-	_	
		I <sub>C</sub> = 10 mA	4000	-	_	
		I <sub>C</sub> = 100 mA	10000	-	_	
		I <sub>C</sub> = 500 mA	2000	_	_	
V <sub>CEsat</sub>	collector-emitter saturation voltage	I <sub>C</sub> = 100 mA; I <sub>B</sub> = 0.1 mA	_	-	1	V
V <sub>BEsat</sub>	base-emitter saturation voltage	I <sub>C</sub> = 100 mA; I <sub>B</sub> = 0.1 mA	_	_	1.5	٧
V <sub>BEon</sub>	base-emitter on-state voltage	I <sub>C</sub> = 10 mA; V <sub>CE</sub> = 5 V	_	_	1.4	٧
f <sub>T</sub>	transition frequency	$I_C = 30 \text{ mA}; V_{CE} = 5 \text{ V}; f = 100 \text{ MHz}$	_	220	_	MHz

2004 Dec 06

# NPN Darlington transistors

BCV29; BCV49



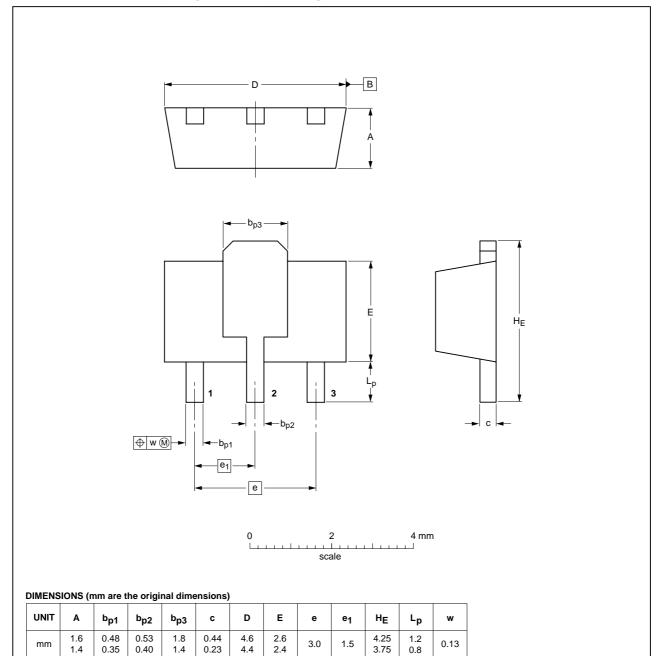
# NPN Darlington transistors

BCV29; BCV49

### **PACKAGE OUTLINE**

Plastic surface-mounted package; collector pad for good heat transfer; 3 leads

SOT89



OUTLINE	REFERENCES			EUROPEAN	ISSUE DATE		
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE	
SOT89		TO-243	SC-62			<del>04-08-03</del> 06-03-16	

### NPN Darlington transistors

**BCV29**; **BCV49** 

#### **DATA SHEET STATUS**

DOCUMENT STATUS <sup>(1)</sup>	PRODUCT STATUS <sup>(2)</sup>	DEFINITION
Objective data sheet	Development	This document contains data from the objective specification for product development.
Preliminary data sheet	Qualification	This document contains data from the preliminary specification.
Product data sheet	Production	This document contains the product specification.

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### **Contact information**

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